

#### **30V P-Channel Enhancement Mode MOSFET**

Voltage

Current -35 A

#### Features

•  $R_{DS(ON)}$ ,  $V_{GS}@-10V$ ,  $I_D@-10A < 15.5m\Omega$ 

-30 V

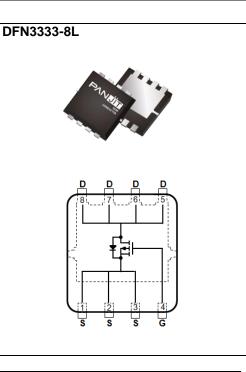
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V$ ,  $I_D@-6A < 23m\Omega$
- High switching speed
- Improved dv/dt capability
- Low gate charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

#### **Mechanical Data**

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.03 grams

#### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage Gate-Source Voltage		V <sub>DS</sub>	-30	V
		V <sub>GS</sub>	<u>+</u> 20	V
Continuous Drain Current	T <sub>C</sub> =25°C		-35	
	Tc=100°C	lD	-22	А
Pulsed Drain Current <sup>(Note 1)</sup>	Tc=25°C	I <sub>DM</sub>	-140	
Power Dissipation	Tc=25°C	D-	30	24/
	Tc=100°C	PD -	11	W
Continuous Drain Current	T <sub>A</sub> =25°C		-9.8	
	T <sub>A</sub> =70°C	I <sub>D</sub>	-7.8	— A
Power Dissipation	T <sub>A</sub> =25°C	D	2.0	24/
Power Dissipation	T <sub>A</sub> =70°C	PD -	1.3	W
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	°C
Typical Thermal Resistance <sup>(Note 4,5)</sup>	Junction to Case	R <sub>ejc</sub>	4.2	
	Junction to Ambient	R <sub>0JA</sub>	62.5	•C/W





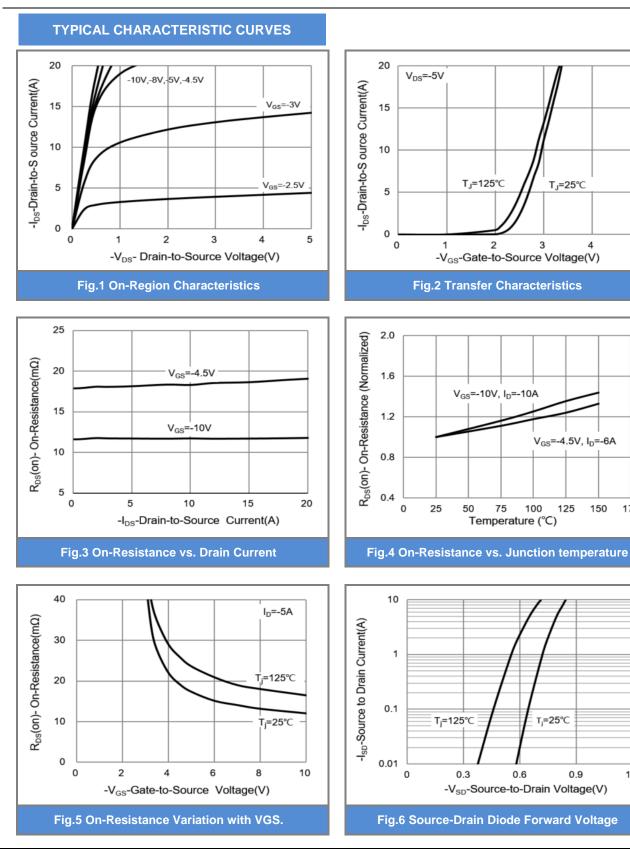
#### Electrical Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
	STWBUL	TEST CONDITION	IVIIIN.	ITF.	IVIAA.	
Static	51					
Drain-Source Breakdown Voltage	BV <sub>DSS</sub> V <sub>GS</sub> =0V,I <sub>D</sub> =-250u	Vgs=0V,Id=-250uA	-30	-	-	v
Gate Threshold Voltage	VGS(th)	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =-250uA	-1.0	-1.6	-2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-10A	-	12	15.5	mΩ
		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-6A	-	18	23	
Zero Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =-30V,V <sub>GS</sub> =0V	-	-	-1.0	uA
Gate-Source Leakage Current	lgss	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA
Dynamic <sup>(Note 6)</sup>						
Total Gate Charge	Qg	V <sub>DS</sub> =-15V, I <sub>D</sub> =-8A, V <sub>GS</sub> =-4.5V <sup>(Note 1,2)</sup>	-	15	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	4	-	
Gate-Drain Charge	$Q_{gd}$		-	6	-	
Input Capacitance	Ciss	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1730	-	pF
Output Capacitance	Coss		-	180	-	
Reverse Transfer Capacitance	Crss		-	125	-	
Turn-On Delay Time	td <sub>(on)</sub>	V <sub>DD</sub> =-15V, I <sub>D</sub> =-1A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω	-	9	-	
Turn-On Rise Time	tr		-	22	-	ns
Turn-Off Delay Time	td <sub>(off)</sub>		-	60	-	
Turn-Off Fall Time	t <sub>f</sub>		-	14	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	-35	А
Diode Forward Current	ls					
Diode Forward Voltage	V <sub>SD</sub>	Is=-1A,V <sub>GS</sub> =0V	-	-0.7	-1	V

NOTES :

- 1. Pulse width <300us, Duty cycle <2%.
- 2. Essentially independent of operating temperature typical characteristics.
- Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub> =25°C.
- 4. The maximum current rating is package limited.
- 5. R<sub>®JA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. Guaranteed by design, not subject to production testing.





1.2

0.9

T**J=25°**C

125

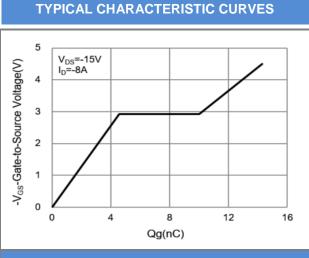
150

4

5

175







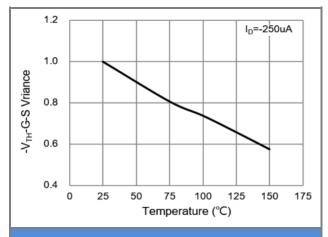
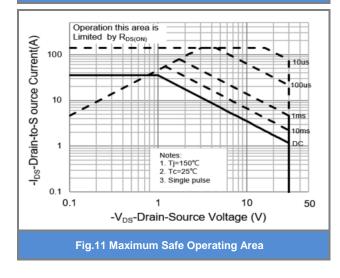
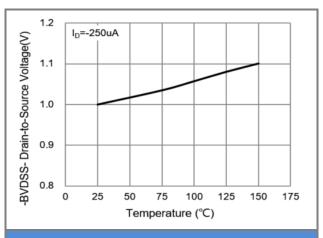


Fig.9 Threshold Voltage Variation with Temperature







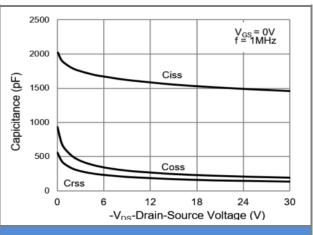
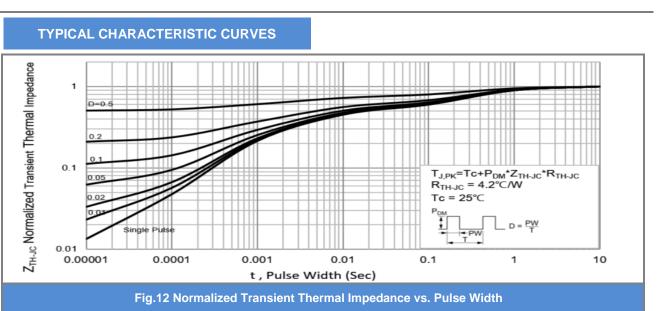


Fig.10 Capacitance vs. Drain-Source Voltage



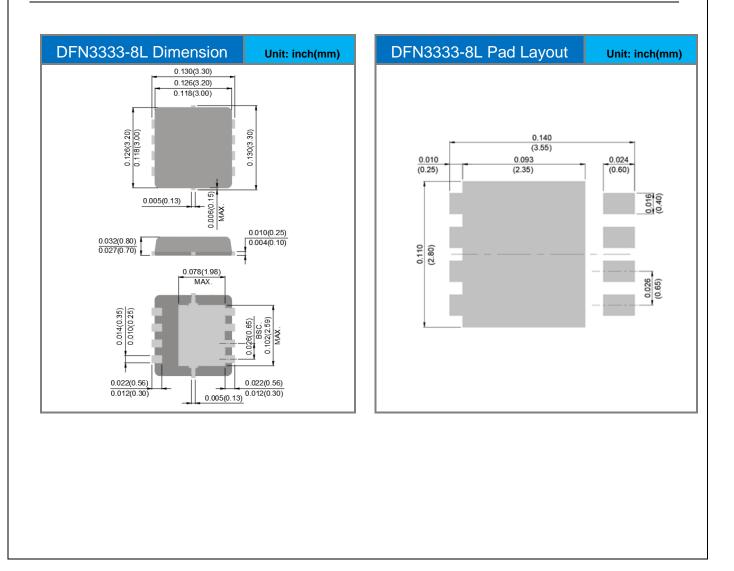




#### Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJQ4403P_R2_00001	DFN3333-8L	5K pcs / 13" reel	4403	Halogen free RoHS compliant

#### **Packaging Information & Mounting Pad Layout**





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